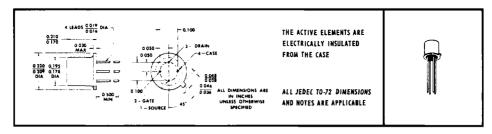
TYPES 2N3909, 2N3909A P-CHANNEL SILICON JUNCTION FIELD-EFFECT TRANSISTORS

BULLETIN NO. DL-S 6810915, SEPTEMBER 1968

ELECTRICALLY SIMILAR TO 2N2386 AND 2N2386A FOR AUDIO- TO HIGH-FREQUENCY SMALL-SIGNAL AMPLIFIERS 2N3909A offers greatly improved y, /C, ratio resulting from process innovation:

- |y_{fs}| Min Raised from 1 mmho to 2.2 mmho
 C_{rss} Max Lowered from 16 pF to 3 pF

*mechanical data



*absolute maximum ratings at 25°C free-air temperature (unless otherwise noted)

Drain-Gate Voltage			. –20 V
Drain-Source Voltage			–20 V
Reverse Gate-Source Voltage			20 V
Continuous Forward Gate Current			–10 mA
Continuous Device Dissipation at (or below) 25°C Free-Air Temperature (See Note 1)			300 mW
Storage Temperature Range		65	5°C to 200°C
Lead Temperature 1/4 Inch from Case for 10 Seconds			300°C

*electrical characteristics at 25°C free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS;		2N3909		2N3909A	
				MAX	MIN	MAX	UNIT
V _{(BR)GSS}	Gate-Source Breakdown Voltage	$I_{G} = 10 \ \mu \text{A}, \ \ V_{DS} = 0$	20	-	20		٧
less	Gate Reverse Current	$V_{GS} = 10 \text{ V}, V_{DS} = 0$		10		10	nA
		$V_{GS} = 10 \text{ V}, V_{DS} = 0, \qquad T_A = 100 ^{\circ}\text{C}$		ì		i	μΑ
V _{GS(off)}	Gate-Source Cutoff Voltage	$V_{DS} = -10 \text{ V}, I_{D} = -10 \mu \text{A}$		8		8	٧
V _{GS}	Gate-Source Voltage	$V_{DS} = -10 \text{ V}, I_D = -30 \mu\text{A}$	0.3	7.9	0.3	7.9	V
IDSS	Zero-Gate-Voltage Drain Current	$V_{DS} = -10 \text{ V}, V_{GS} = 0$	-0.3	-15	-1	-15	mA
y _{fs}	Small-Signal Common-Source Forward Transfer Admittance	$V_{DS} = -10 \text{ V},$	1	5	2.2	5	mmho
Yos	Small-Signal Common-Source Output Admittance	$V_{\Theta S}=0,$ $F=1$ kHz		0.1		0.1	mmho
C,ss	Common-Source Short-Circuit Input Capacitance	$V_{DS} = -10 \text{ V},$ $V_{GS} = 0,$ $f = 1 \text{ MHz}$		32		9	pF
Crss	Comman-Source Short-Circuit Reverse Transfer Capacitance			16		3	рF
y _{fs}	Small-Signal Common-Source Forward Transfer Admittance	$V_{DS} = -10 \text{ V}, V_{GS} = 0, f = 10 \text{ MHz}$	0.9		2		mmho

NOTE 1: Derate linearly to 175°C free-air temperature at the rate of 2 mW/°C

\$\pm\$The fourth lead (case) is connected to the source for all measurements.

USES CHIP JP71

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^{*}Indicates JEDEC registered data